

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FDD86581

FEATURES

- Drain Current : I_D=25A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage
 : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 15m Ω (Max) @V_{GS}= 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

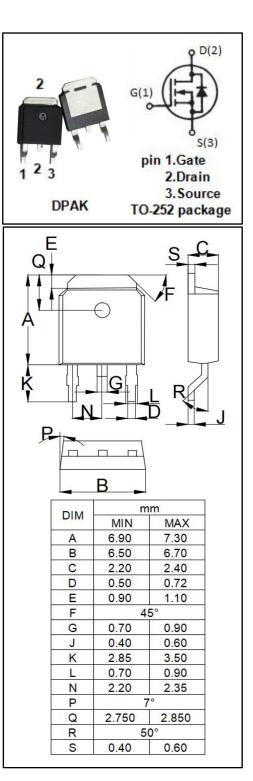
 motor drive, DC-DC converter, power switch and solenoid drive.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	60	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
ID	Drain Current-Continuous	25	A
Ідм	Drain Current-Single Pluse	100	A
P _D	Total Dissipation @T _c =25℃	48.4	W
TJ	Max. Operating Junction Temperature	-55~175	°C
T _{stg}	Storage Temperature	-55~175	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.1	°C /W



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	60	-	V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =25A	-	15	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0	-	±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60V; V _{GS} = 0	-	1.0	uA
V_{SD}	Forward On-Voltage	I _S =12.5A; V _{GS} = 0	-	1.2	V
V_{SD}	Forward On-Voltage	I _S =25A; V _{GS} = 0	-	1.3	V

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